





ZXTN620MA

80V NPN LOW SATURATION TRANSISTOR

Features and Benefits

- BV_{CEO} > 80V
- I_C = 3.5A Continuous Collector Current
- Low Saturation Voltage (185mV max @ 1A)
- R_{SAT} = 68 mΩ for a low equivalent On-Resistance
- hFE specified up to 5A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R₀JA efficient, 60% lower than SOT23
- 4mm² footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

Applications

- MOSFET Gate Driving
- DC-DC Converters
- Charging circuits
- Motor Control
- Power switches

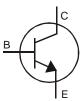
DFN2020B-3



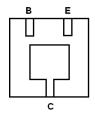
Top View



Bottom View



Device Symbol



Bottom View Pin-Out

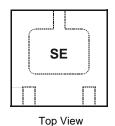
Ordering Information

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN620MATA	SE	7	8	3000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com

Marking Information



SE = Product Type Marking code





ZXTN620MA

Maximum Ratings @T_A = 25°C unless otherwise specified

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		V _{CBO}	100	V	
Collector-Emitter Voltage		V _{CEO}	80		
Emitter-Base Voltage		V _{EBO}	7		
Peak Pulse Current		I _{CM}	5		
Continuous Collector Current	(Note 3)	I-	3.5	۸	
	(Note 4)	Ic	3.8	^	
Base Current		I _B	1		

Thermal Characteristics @TA = 25°C unless otherwise specified

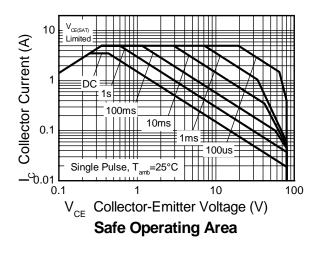
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 3)	D	1.5 12	W	
Linear Derating Factor	(Note 4)	P _D	2.45 19.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 3)	Б	83	°C/W	
Thermal Resistance, Junction to Ambient	(Note 4)	R_{\thetaJA}	51		
Thermal Resistance, Junction to Lead	(Note 5)	$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

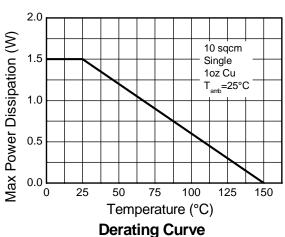
Notes:

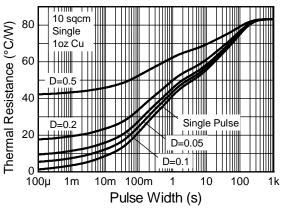
- 3. For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
- Same as note (3), except the device is measured at t ≤ 5 sec.
- 5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

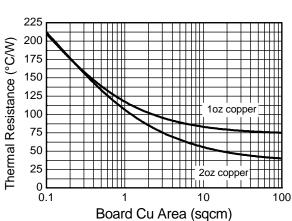


Thermal Characteristics



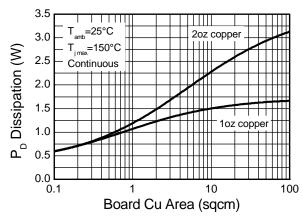






Transient Thermal Impedance

Thermal Resistance v Board Area



Power Dissipation v Board Area



ZXTN620MA

Electrical Characteristics @TA = 25°C unless otherwise specified

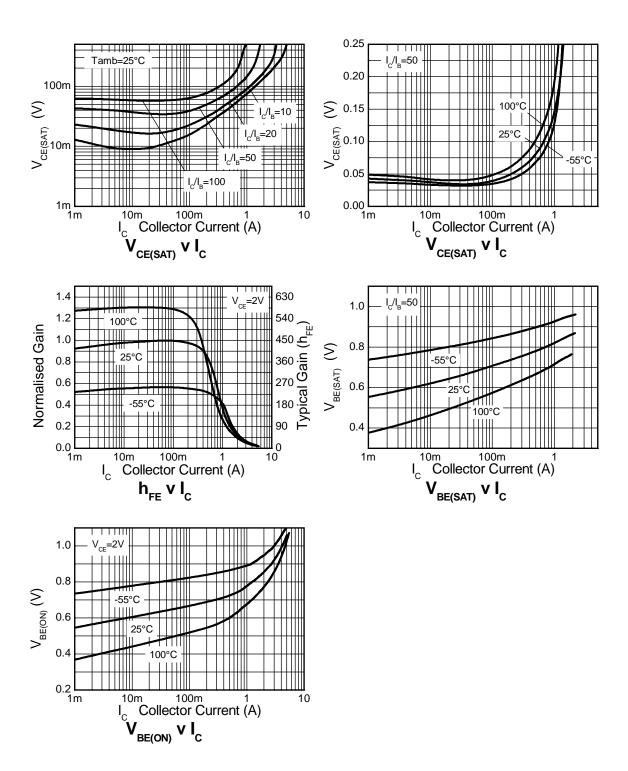
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	180	-	V	I _C = 100 μA
Collector-Emitter Breakdown Voltage (Note 6)	BV _{CEO}	80	110	-	V	I _C = 10 mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.2	-	V	I _E = 100 μA
Collector Cutoff Current	I _{CBO}	-	-	100	nA	V _{CB} = 80V
Emitter Cutoff Current	I _{EBO}	-	-	100	. nA	V _{EB} = 6V
Collector Emitter Cutoff Current	I _{CES}	-	-	100	nA	V _{CE} = 65V
Static Forward Current Transfer Ratio (Note 6)	h _{FE}	200 300 110 60 20	450 450 170 90 30 10	- 900 - - - -	-	$\begin{split} &I_{C} = 10 \text{mA}, V_{CE} = 2 \text{V} \\ &I_{C} = 200 \text{mA}, V_{CE} = 2 \text{V} \\ &I_{C} = 1 \text{A}, V_{CE} = 2 \text{V} \\ &I_{C} = 1.5 \text{A}, V_{CE} = 2 \text{V} \\ &I_{C} = 3 \text{A}, V_{CE} = 2 \text{V} \\ &I_{C} = 5 \text{A}, V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 6)	$V_{CE(sat)}$	- - - -	15 45 145 160 240	20 60 185 200 340	mV	$\begin{split} &I_C = 0.1 \text{A}, \ I_B = 10 \text{mA} \\ &I_C = 0.5 \text{A}, \ I_B = 50 \text{mA} \\ &I_C = 1 \text{A}, \ I_B = 20 \text{mA} \\ &I_C = 1.5 \text{A}, \ I_B = 50 \text{mA} \\ &I_C = 3.5 \text{A}, \ I_B = 300 \text{mA} \end{split}$
Base-Emitter Turn-On Voltage (Note 6)	V _{BE(on)}	-	0.96	1.05	V	$I_C = 3.5A, V_{CE} = 2V$
Base-Emitter Saturation Voltage (Note 6)	V _{BE(sat)}	-	1.09	1.175	V	$I_C = 3.5A$, $I_B = 300mA$
Output Capacitance	C _{obo}	-	11.5	18	pF	V _{CB} = 10V. f = 1MHz
Transition Frequency	f⊤	100	160	-	MHz	V _{CE} = 10V, I _C = 50mA, f = 100MHz
Turn-On Time	t _{on}	-	86	-	ns	V _{CC} = 10V, I _C = 1A
Turn-Off Time	t _{off}	-	1128	-	ns	$I_{B1} = I_{B2} = 25mA$

Notes: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



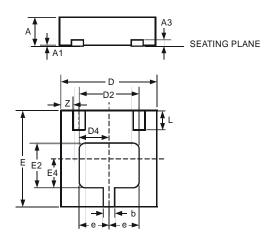


Typical Electrical Characteristics



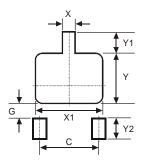


Package Outline Dimensions



DFN2020B-3					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0	0.05	0.02		
A3	_	_	0.152		
b	0.20	0.30	0.25		
D	1.95	2.075	2.00		
D2	1.22	1.42	1.32		
D4	0.56	0.76	0.66		
е	_	_	0.65		
Е	1.95	2.075	2.00		
E2	0.79	0.99	0.89		
E4	0.48	0.68	0.58		
L	0.25	0.35	0.30		
Z			0.225		
All Dimensions in mm					

Suggested Pad Layout



Dimensions	Value (in mm)		
С	1.30		
G	0.24		
Х	0.35		
X1	1.52		
Υ	1.09		
Y1	0.47		
Y2	0.50		





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